

CMS Power-lines Protection Series (CMS-P)

Descriptions

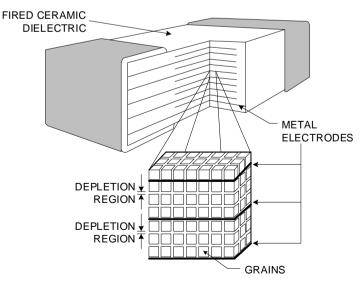
The Ceramic Micro-Surge Protection Device (CMS) is manufactured from semiconducting ceramics which offer rugged protection and excellent transient energy absorption in a small SMD package. These devices are designed to suppress a variety of transient events, including those speified in IEC61000-4-2, IEC61000-4-5 and other standards used for Electromagnetic Compliance (EMC).

These devices are available in ceramic leadless chip form, eliminating lead inductance and assuring fast speed of response to transient surges. In addition, The CMS transient suppressors have temperature independent suppression characteristics, affording protection from -55 $^{\circ}$ C to 125 $^{\circ}$ C, which is much better than suppressors based on silicon semiconductor technology.

The CMS-P Series is specially designed for power-lines protection applications. It features a very high current protection capability with a very small size, also a very fast response thus a ultra low clamping voltage. These characteristics make CMS-P Series devices the best replacement of TVS and metal oxide (MOV).

Features

- Multi-Layers Construction Provides Higher Power Dissipation
- Surge Current Capability: 5000A (@8/20µs)
- Better than UL94V-0 Flammability Rating
- No Temperature Derating up to 125°C Ambient
- Reliable ESD Protection up to 30kV acc. to IEC61000-4-2
- Inherent Bi-directional Clamping
- SMD type Body size 2220
- "Zero" Lead Inductance
- Very low Clamping Voltage
- RoHS compliant



Multilayer Internal Construction



Top View

Order Information

Туре	Quantity	Reel Size
CMS2220	2000 pcs	13 Inch
CIVISZZZU	2000 pcs	(330mm)

Applications

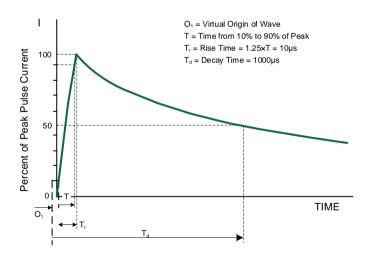
- Severe transient voltage suppressor for power-lines, replacing traditional MOV&TVS solutions.
- Surge protection for IEC61000-4-5
- EFT protection for IEC 61000-4-4 (Level 4)
- ESD protection for IEC 61000-4-2 (Level 4)



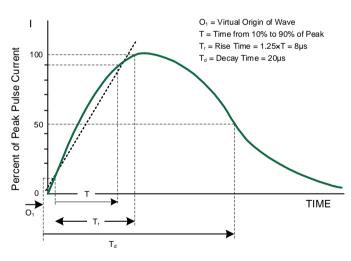
Device Ratings and Specifications

Parameter	Symbol	Condition	Value	Unit
Maximum Continuous a.c. Voltage	V _{M(AC)}	50~60Hz	50	V
Maximum Continuous d.c. Voltage	V _{M(DC)}		65	V
Nominal Varistor Voltage	V_N	@1mA	73~91	V
Maximum Leakage Current	lι	@V _M	30	μΑ
Maximum Clamping Voltage	Vc	@lc	135	V
Class Current	Ic	tp = 8/20µs	10	А
Peak Pulse Current	l _{PP}	tp = 8/20µs	5000	А
Rated Energy	Ем	10/1000µs	18	J
Operating Temperature Range		_	-55 to +125	°C
Storage Temperature			-55 to +150	°C

Pulse Waveform - 10/1000µs waveform

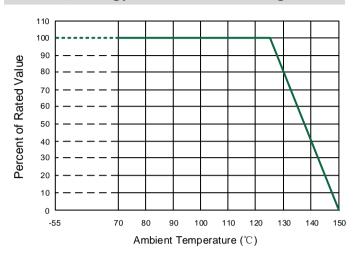


Pulse Waveform - 8/20µs waveform

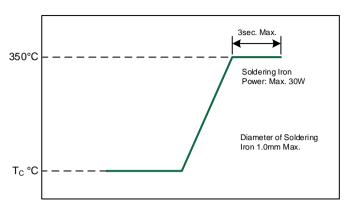




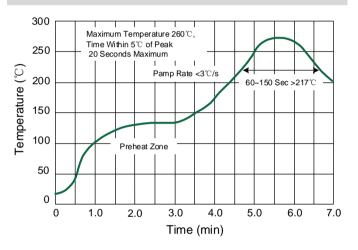
Current, Energy and Power Derating Curve



Iron Soldering Profile



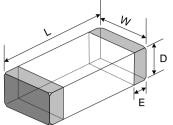
Lead-free Re-flow Solder Profile



Solder-resist



Product Dimensions



C Land Pattern

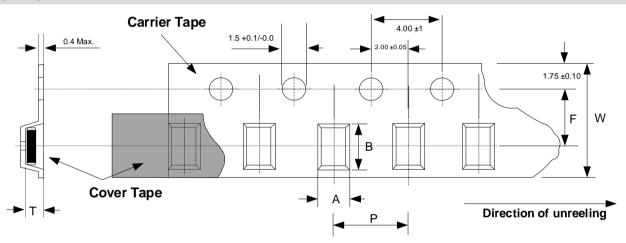
Product Dimensions

Recommended PCB Pattern

CMS Device

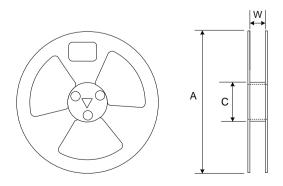
Size	L	w	D Max	E	A	В	С
2220	6.00+0.70/-0.30	5.30+0.50/-0.30	4.0	0.25~1.3	4.0~4.2	1.8~2.0	5.2~5.8

Tape Specifications



Туре	Α	В	Т	Р	w	F
CMS2220	5.90±0.20	6. 80±0.20	4.20Max.	8.00 ±0.10	12.00 ±0.20	5.50 ±0.05

Reel Dimension



Type	Spec.	Dimensions(mm)		
Туре	эрес.	Α	W	С
CMS2220	13"	330	12.4+2.0/-0.0	100



Storage

- Storage temperature range (packaging conditions): -10°C~+40°C RH 70% (Max.).
- The solderability of the external electrode may be deteriorated if packages are stored where they are exposed to high humidity. Package must be stored at 40°C or less and 70% RH or less.
- The solderability of the external electrode may be deteriorated if packages are stored where they are exposed to dust of harmful gas (e.g. HCl, sulfurous gas of H₂S).
- Packaging material may be deformed if package are stored where they are exposed to heat of direct sunlight.
- Solderability shall be guaranteed for 12 months from the date of delivery on condition that they are stored at the environment specified in Clause 2. For those parts, which passed more than 12 months shall be checked solder-ability before use.

Environmental Reliability Test

Item	Requirment	Test Condition
High Temperature Storage	 Breakdown voltage change: within ±10% No mechanical damage 	 Temperature: 150 ± 2°C Time: 1000 (+24) hours Test after placing in ambient temperature for 1~2hours
Low Temperature Storage	Breakdown voltage change: within ±10% No mechanical damage	 Temperature: -55± 2°C Time: 1000 (+24) hours Test after placing in ambient temperature for 1~2hours
Thermal Shock	 Breakdown voltage change: within ±10% No mechanical damage 	 Temperature, Time:-55 (±2) °C/30min~ 125 (±2) °C/30min Transforming interval: 2~3min. Tested cycle: 100 cycles. Test after placing in ambient temperature for 1~2hours
High Temperature Load	Breakdown voltage change: within ±10% No mechanical damage	 Temperature: 125 ± 2^oC Rated working voltage applied Time: 1000 (+24) hours Test after placing in ambient temperature for 1~2hours
Damp Heat Load / Humidity Load	 Breakdown voltage change: within ±10% No mechanical damage 	 Temperature: 85±2℃ Humidity: 85%±2RH Rated working voltage applied Time: 500 (+24) hours Test after placing in ambient temperature for 1~2hours

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Specifications are subject to change without notice.

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